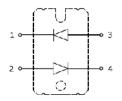


PRELIMINARY DATASHEET

Anti-Parallel Fast Recovery, 2x100A, 600V Diodes In Isolated SOT227 Package

- Fast recovery
- Soft switching
- Low forward voltage
- RoHS compliant
- Easy paralleling





MAXIMUM RATINGS (per Diode), at T_i = 25°C, unless otherwise specified

Parameter	Symbol	Value	Units	
Repetitive peak reverse voltage	V_{RRM}	600	V	
Continuous forward current $T_c = 80 ^{\circ}\text{C}$	I _F	100	٨	
Maximum repetitive forward current $T_C = 25^{\circ}C$, t_P limited by T_{jmax} , $D = 0.5$	I _{FRM}	200	A	
Operating junction and storage temperature	T _j , T _{stg}	-55 +175	°C	

Thermal and Isolation Characteristics

Parameter	Symbol	Max. Value	Units
Characteristics			
Thermal resistance, junction to case, per Diode	R _{thJC}	0.80	°C/W
Thermal resistance, junction to ambient	R_{thJA}	40	
Isolation voltage, RMS (measured between terminals and mounting base, 50-60 Hz, for 1-3 seconds)	V _{iso}	3000	٧

Electrical Characteristics (per Diode), at T_j = 25°C, unless otherwise specified

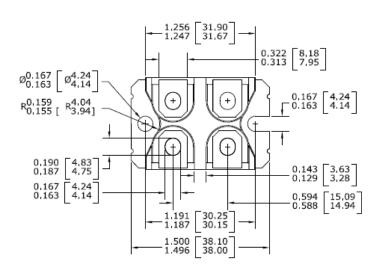
Parameter	Symbol	Value			11
		Min.	Тур.	Max.	Unit
Static Characteristics					
Reverse leakage current VR = 600V, T _j = 25°C	I _R	-	-	27	μA
Forward voltage drop IF = 100A, T _j = 25°C IF = 100A, T _j = 150°C	VF		1.6 1.5	2.0	V

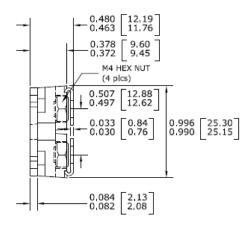
Electrical Characteristics (per Diode), at T_j = 25°C, unless otherwise specified

Parameter	Symbol	Value			11!
		Min.	Тур.	Max.	Unit
Dynamic Characteristics					
Reverse recovery time $V_R = 400V$, $I_F = 100A$, $di_F/dt = 1300A/\mu s$, $V_{GE} = -15V$ $T_j = 25^{\circ}C$	† _{rr}	-	70	-	ns
Peak reverse recovery current $V_R = 400V$, $I_F = 100A$, $di_F/dt = 1300A/\mu s$, $V_{GE} = -15V$ $T_j = 25^{\circ}C$ $V_R = 400V$, $I_F = 100A$, $di_F/dt = 1300A/\mu s$, $V_{GE} = -15V$ $T_j = 125^{\circ}C$	I _{rrm}	-	50 60		Α
Recovered charge $V_R = 400V$, $I_F = 100A$, $di_F/dt = 1300A/\mu s$, $V_{GE} = -15V$ $T_j = 25^{\circ}C$ $V_R = 400V$, $I_F = 100A$, $di_F/dt = 1300A/\mu s$, $V_{GE} = -15V$ $T_j = 125^{\circ}C$	Qr	-	3.0 6.3	-	μC
Reverse recovery energy $V_R = 400V$, $I_F = 100A$, $di_F/dt = 1300A/\mu s$, $V_{GE} = -15V$ $T_j = 25^{\circ}C$ $V_R = 400V$, $I_F = 100A$, $di_F/dt = 1300A/\mu s$, $V_{GE} = -15V$ $T_j = 125^{\circ}C$	E _{rec}	-	0.5 1.05	-	mJ



Package Outline Drawing





Disclaimer

These specifications may not be considered as a guarantee of components characteristics. Components have to be tested depending on intended application as adjustments may be necessary. The use of **iQXPRZ Power Inc.** components in life support appliances and systems are subject to written approval of **iQXPRZ Power Inc.**